

# Ultralow Noise, 200 mA, CMOS Linear Regulator

Data Sheet ADP151

#### **FEATURES**

Ultralow noise: 9 µV rms

No noise bypass capacitor required

Stable with 1  $\mu$ F ceramic input and output capacitors

Maximum output current: 200 mA Input voltage range: 2.2 V to 5.5 V

Low quiescent current I<sub>GND</sub> = 10 μA with 0 load

 $I_{GND} = 265 \mu A$  with 200 mA load

Low shutdown current: <1 µA

Low dropout voltage: 140 mV at 200 mA load

Initial accuracy: ±1%

Accuracy over line, load, and temperature: ±2.5% 16 fixed output voltage options: 1.1 V to 3.3 V

PSRR performance of 70 dB at 10 kHz

**Current-limit and thermal overload protection** 

Logic controlled enable

Internal pull-down resistor on EN input

5-lead TSOT package

6-lead LFCSP package

4-ball, 0.4 mm pitch WLCSP

#### **APPLICATIONS**

RF, VCO, and PLL power supplies
Mobile phones
Digital camera and audio devices
Portable and battery-powered equipment
Post dc-to-dc regulation
Portable medical devices

#### **GENERAL DESCRIPTION**

The ADP151 is an ultralow noise, low dropout linear regulator that operates from 2.2 V to 5.5 V and provides up to 200 mA of output current. The low 140 mV dropout voltage at 200 mA load improves efficiency and allows operation over a wide input voltage range.

Using an innovative circuit topology, the ADP151 achieves ultralow noise performance without the necessity of a bypass capacitor, making it ideal for noise-sensitive analog and RF applications. The ADP151 also achieves ultralow noise performance without compromising PSRR or transient line and load performance. The low 265  $\mu A$  of quiescent current at 200 mA load makes the ADP151 suitable for battery-operated portable equipment.

The ADP151 also includes an internal pull-down resistor on the EN input.

#### Rev. E

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

#### TYPICAL APPLICATION CIRCUIT

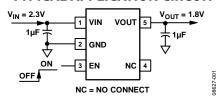


Figure 1. TSOT ADP151 with Fixed Output Voltage, 1.8 V

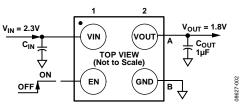


Figure 2. WLCSP ADP151 with Fixed Output Voltage, 1.8 V

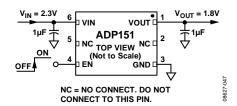


Figure 3. LFCSP ADP151 with Fixed Output Voltage, 1.8 V

The ADP151 is specifically designed for stable operation with tiny 1  $\mu$ F,  $\pm 30\%$  ceramic input and output capacitors to meet the requirements of high performance, space constrained applications.

The ADP151 is capable of 16 fixed output voltage options, ranging from 1.1 V to 3.3 V.

Short-circuit and thermal overload protection circuits prevent damage in adverse conditions. The ADP151 is available in tiny 5-lead TSOT, 6-lead LFCSP, and 4-ball, 0.4 mm pitch, halide-free WLCSP packages for the smallest footprint solution to meet a variety of portable power application requirements.

# ADP151\* PRODUCT PAGE QUICK LINKS

Last Content Update: 04/08/2017

## COMPARABLE PARTS 🖳

View a parametric search of comparable parts.

## **EVALUATION KITS**

- · ADP151 Evaluation Board
- FPGA Mezzanine Card for Wireless Communications

## **DOCUMENTATION**

## **Application Notes**

 AN-1072: How to Successfully Apply Low Dropout Regulators

#### **Data Sheet**

- · ADP151-DSCC: Military Data Sheet
- · ADP151-EP: Enhanced Product Data Sheet
- ADP151: Ultralow Noise, 200 mA, CMOS Linear Regulator Datasheet

#### **User Guides**

- UG-090: RedyKit<sup>™</sup> for the ADP151 LDO
- UG-116: Setting Up the Evaluation Board for the ADP151

## TOOLS AND SIMULATIONS $\Box$

- ADI Linear Regulator Design Tool and Parametric Search
- ADIsimPower™ Voltage Regulator Design Tool

## REFERENCE DESIGNS 🖵

- CN0190
- CN0308
- CN0369
- CN0371

## DESIGN RESOURCES

- ADP151 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- · Symbols and Footprints

## **DISCUSSIONS**

View all ADP151 EngineerZone Discussions.

## SAMPLE AND BUY 🖳

Visit the product page to see pricing options.

## TECHNICAL SUPPORT 🖳

Submit a technical question or find your regional support number.

## DOCUMENT FEEDBACK 🖵

Submit feedback for this data sheet.

# **TABLE OF CONTENTS**

Features1
Applications1
Typical Application Circuit1
General Description1
Revision History2
Specifications
Input and Output Capacitor, Recommended Specifications 4
Absolute Maximum Ratings5
Thermal Data5
Thermal Resistance
ESD Caution5
Pin Configurations and Function Descriptions 6
REVISION HISTORY
4/12—Rev. D to Rev. E
Changes to Figure 33
Updated Outline Dimensions
Changes to Ordering Guide
3/11—Rev. C to Rev. D
Changes to Current-Limit Threshold Temperature Range 4
Added EPAD Notation6
Changes to Ordering Guide
1/11—Rev. B to Rev. C
Changes to Figure 239
12/10—Rev. A to Rev. B
Added LFCSP PackageUniversal
Added Figure 3; Renumbered Sequentially 1
Added Table 2 Caption; Renumbered Sequentially4
Changes to Table 45
Added Figure 6, Changes to Table 56
Changes to Figure 239
Changes to Figure 37 and Figure 3814

Theory of Operation       11         Applications Information       12         Capacitor Selection       12         Enable Feature       13         Adjustable Output Voltage Operation       13         Current-Limit and Thermal Overload Protection       15         Thermal Considerations       20         Outline Dimensions       21         Ordering Guide       22         Added Figure 59       19         Added Figure 62       20         Added Figure 65       21         Updated Outline Dimensions       21         Changes to Ordering Guide       23         8/10—Rev. 0 to Rev. A       Changes to Figure 15 Caption and Figure 16 Caption       8         Changes to Figure 17 Caption and Figure 18 Caption       9         Changes to Ordering Guide       21	Typical Performance Characteristics7
Capacitor Selection       12         Enable Feature       13         Adjustable Output Voltage Operation       13         Current-Limit and Thermal Overload Protection       15         Thermal Considerations       15         Printed Circuit Board Layout Considerations       20         Outline Dimensions       21         Ordering Guide       22         Added Figure 59       19         Added Figure 62       20         Added Figure 65       21         Updated Outline Dimensions       21         Changes to Ordering Guide       23         8/10—Rev. 0 to Rev. A       23         Changes to Figure 8       7         Changes to Figure 15 Caption and Figure 16 Caption       8         Changes to Figure 17 Caption and Figure 18 Caption       9	Theory of Operation
Enable Feature       13         Adjustable Output Voltage Operation       13         Current-Limit and Thermal Overload Protection       15         Thermal Considerations       15         Printed Circuit Board Layout Considerations       20         Outline Dimensions       21         Ordering Guide       22         Added Figure 59       19         Added Figure 65       21         Updated Outline Dimensions       21         Changes to Ordering Guide       23         8/10—Rev. 0 to Rev. A         Changes to Figure 8       7         Changes to Figure 15 Caption and Figure 16 Caption       8         Changes to Figure 17 Caption and Figure 18 Caption       9	Applications Information
Adjustable Output Voltage Operation	Capacitor Selection
Current-Limit and Thermal Overload Protection       15         Thermal Considerations       15         Printed Circuit Board Layout Considerations       20         Outline Dimensions       21         Ordering Guide       22         Added Figure 51 to Figure 56       18         Added Figure 62       20         Added Figure 65       21         Updated Outline Dimensions       21         Changes to Ordering Guide       23         8/10—Rev. 0 to Rev. A         Changes to Figure 8       7         Changes to Figure 15 Caption and Figure 16 Caption       8         Changes to Figure 17 Caption and Figure 18 Caption       9	Enable Feature
Thermal Considerations	Adjustable Output Voltage Operation
Printed Circuit Board Layout Considerations       20         Outline Dimensions       21         Ordering Guide       22         Added Figure 51 to Figure 56       18         Added Figure 59       19         Added Figure 62       20         Added Figure 65       21         Updated Outline Dimensions       21         Changes to Ordering Guide       23         8/10—Rev. 0 to Rev. A         Changes to Figure 8       7         Changes to Figure 15 Caption and Figure 16 Caption       8         Changes to Figure 17 Caption and Figure 18 Caption       9	Current-Limit and Thermal Overload Protection
Outline Dimensions       21         Ordering Guide       22         Added Figure 51 to Figure 56       18         Added Figure 59       19         Added Figure 62       20         Added Figure 65       21         Updated Outline Dimensions       21         Changes to Ordering Guide       23         8/10—Rev. 0 to Rev. A         Changes to Figure 8       7         Changes to Figure 15 Caption and Figure 16 Caption       8         Changes to Figure 17 Caption and Figure 18 Caption       9	Thermal Considerations
Ordering Guide       22         Added Figure 51 to Figure 56       18         Added Figure 59       19         Added Figure 62       20         Added Figure 65       21         Updated Outline Dimensions       21         Changes to Ordering Guide       23         8/10—Rev. 0 to Rev. A         Changes to Figure 8       7         Changes to Figure 15 Caption and Figure 16 Caption       8         Changes to Figure 17 Caption and Figure 18 Caption       9	Printed Circuit Board Layout Considerations
Added Figure 51 to Figure 56       18         Added Figure 59       19         Added Figure 62       20         Added Figure 65       21         Updated Outline Dimensions       21         Changes to Ordering Guide       23         8/10—Rev. 0 to Rev. A         Changes to Figure 8       7         Changes to Figure 15 Caption and Figure 16 Caption       8         Changes to Figure 17 Caption and Figure 18 Caption       9	Outline Dimensions
Added Figure 59       19         Added Figure 62       20         Added Figure 65       21         Updated Outline Dimensions       21         Changes to Ordering Guide       23         8/10—Rev. 0 to Rev. A         Changes to Figure 8       7         Changes to Figure 15 Caption and Figure 16 Caption       8         Changes to Figure 17 Caption and Figure 18 Caption       9	Ordering Guide22
Added Figure 59       19         Added Figure 62       20         Added Figure 65       21         Updated Outline Dimensions       21         Changes to Ordering Guide       23         8/10—Rev. 0 to Rev. A         Changes to Figure 8       7         Changes to Figure 15 Caption and Figure 16 Caption       8         Changes to Figure 17 Caption and Figure 18 Caption       9	
Added Figure 59       19         Added Figure 62       20         Added Figure 65       21         Updated Outline Dimensions       21         Changes to Ordering Guide       23         8/10—Rev. 0 to Rev. A         Changes to Figure 8       7         Changes to Figure 15 Caption and Figure 16 Caption       8         Changes to Figure 17 Caption and Figure 18 Caption       9	
Added Figure 59       19         Added Figure 62       20         Added Figure 65       21         Updated Outline Dimensions       21         Changes to Ordering Guide       23         8/10—Rev. 0 to Rev. A         Changes to Figure 8       7         Changes to Figure 15 Caption and Figure 16 Caption       8         Changes to Figure 17 Caption and Figure 18 Caption       9	
Added Figure 62       20         Added Figure 65       21         Updated Outline Dimensions       21         Changes to Ordering Guide       23         8/10—Rev. 0 to Rev. A         Changes to Figure 8       7         Changes to Figure 15 Caption and Figure 16 Caption       8         Changes to Figure 17 Caption and Figure 18 Caption       9	Added Figure 51 to Figure 56
Added Figure 65	Added Figure 59
Updated Outline Dimensions	Added Figure 62
Changes to Ordering Guide	Added Figure 65
8/10—Rev. 0 to Rev. A  Changes to Figure 8	Updated Outline Dimensions
Changes to Figure 8	Changes to Ordering Guide
Changes to Figure 8	8/10—Rev. 0 to Rev. A
Changes to Figure 15 Caption and Figure 16 Caption	
Changes to Figure 17 Caption and Figure 18 Caption9	
	· · · · · · · · · · · · · · · · · · ·

#### 3/10—Revision 0: Initial Version

# **SPECIFICATIONS**

 $V_{\rm IN} = (V_{\rm OUT} + 0.4 \ V) \ or \ 2.2 \ V, \ whichever \ is \ greater; \ EN = V_{\rm IN}, \ I_{\rm OUT} = 10 \ mA, \ C_{\rm IN} = C_{\rm OUT} = 1 \ \mu F, \ T_{\rm A} = 25 ^{\circ} C, \ unless \ otherwise \ noted.$ 

Table 1.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
INPUT VOLTAGE RANGE	V <sub>IN</sub>	$T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	2.2		5.5	٧
OPERATING SUPPLY CURRENT	I <sub>GND</sub>	Ι <sub>ΟυΤ</sub> = 0 μΑ		10		μΑ
		$I_{OUT} = 0 \mu A$ , $T_J = -40^{\circ} C$ to $+125^{\circ} C$			20	μΑ
		Ιουτ = 100 μΑ		20		μΑ
		$I_{OUT} = 100 \mu\text{A}, T_J = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}$			40	μΑ
		I <sub>OUT</sub> = 10 mA		60		μΑ
		$I_{OUT} = 10 \text{ mA}, T_J = -40^{\circ}\text{C to} + 125^{\circ}\text{C}$			90	μΑ
		I <sub>OUT</sub> = 200 mA		265		μΑ
		$I_{OUT} = 200 \text{ mA}, T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}$			350	μΑ
SHUTDOWN CURRENT	I <sub>GND-SD</sub>	EN = GND		0.2		μΑ
		$EN = GND, T_J = -40^{\circ}C \text{ to } +125^{\circ}C$			1.0	μΑ
OUTPUT VOLTAGE ACCURACY						
	V <sub>OUT</sub>	$I_{OUT} = 10 \text{ mA}$	-1		+1	%
TSOT/LFCSP	V <sub>OUT</sub>	$T_{J} = -40^{\circ}\text{C to } +125^{\circ}\text{C}$				
		V <sub>OUT</sub> < 1.8 V				
		$100 \mu A < I_{OUT} < 200 \text{ mA}, V_{IN} = (V_{OUT} + 0.4 \text{ V}) \text{ to } 5.5 \text{ V}$	-3		+2	%
		V <sub>ОUТ</sub> ≥1.8 V				
		$100 \mu A < I_{OUT} < 200 \text{ mA}, V_{IN} = (V_{OUT} + 0.4 \text{ V}) \text{ to } 5.5 \text{ V}$	-2.5		+1.5	%
WLCSP	Vout	$T_J = -40^{\circ}\text{C to } + 125^{\circ}\text{C}$				
		V <sub>OUT</sub> < 1.8 V				
		100 $\mu$ A < $I_{OUT}$ < 200 mA, $V_{IN}$ = ( $V_{OUT}$ + 0.4 V) to 5.5 V	-2.5		+2	%
		V <sub>OUT</sub> ≥1.8 V	_			
		$100 \mu A < I_{OUT} < 200 \text{ mA}, V_{IN} = (V_{OUT} + 0.4 \text{ V}) \text{ to } 5.5 \text{ V}$	-2		+1.5	%
REGULATION		V (V - 0.410) - 5.5V.T - 400C - 14250C	0.05		. 0.05	0/ 0/
Line Regulation	ΔV <sub>OUT</sub> /ΔV <sub>IN</sub>	$V_{IN} = (V_{OUT} + 0.4 \text{ V}) \text{ to } 5.5 \text{ V}, T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	-0.05		+0.05	%/V
Load Regulation (TSOT/LFCSP) <sup>1</sup>	Δ <b>V</b> ουτ/Δ <b>I</b> ουτ	V <sub>OUT</sub> < 1.8 V		0.006		%/mA %/mA
		$I_{OUT} = 100 \mu A$ to 200 mA $I_{OUT} = 100 \mu A$ to 200 mA, $T_J = -40$ °C to +125°C		0.006	0.012	%/mA
		$V_{\text{OUT}} = 100 \mu\text{A to } 200 \text{MA},  V_{\text{J}} = -40 \text{C to} + 125 \text{C}$			0.012	%/IIIA
		$I_{OUT} = 1.00 \mu\text{A}$ to 200 mA		0.003		%/mA
		$I_{OUT} = 100 \mu\text{A} \text{ to } 200 \text{mA}$ $I_{OUT} = 100 \mu\text{A} \text{ to } 200 \text{mA}, T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}$		0.003	0.008	%/mA
Load Regulation (WLCSP) <sup>1</sup>	ΔV <sub>ουτ</sub> /ΔΙ <sub>ουτ</sub>	V <sub>OUT</sub> < 1.8 V			0.000	%/mA
Loud Regulation (WLESI)	Δ • Ο Ο Ι / Δ Ι Ο Ο Ι	$I_{OUT} = 100 \mu\text{A} \text{ to } 200 \text{mA}$		0.004		%/mA
		$I_{OUT} = 100 \mu\text{A} \text{ to } 200 \text{m}\text{A}$ $I_{OUT} = 100 \mu\text{A} \text{ to } 200 \text{mA}, T_J = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}$		0.004	0.009	%/mA
		V <sub>OUT</sub> ≥1.8 V			0.005	70,111,1
		$I_{OUT} = 100 \mu\text{A}$ to 200 mA		0.002		%/mA
		$I_{OUT} = 100 \mu\text{A} \text{ to } 200 \text{mA}, T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}$			0.006	%/mA
DROPOUT VOLTAGE <sup>2</sup>	V <sub>DROPOUT</sub>	I <sub>OUT</sub> = 10 mA		10		mV
		$I_{OUT} = 10 \text{ mA}, T_J = -40^{\circ}\text{C to} + 125^{\circ}\text{C}$		-	30	mV
TSOT/LFCSP		I <sub>OUT</sub> = 200 mA		150		mV
		$I_{OUT} = 200 \text{ mA}, T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}$			230	mV
WLCSP		I <sub>OUT</sub> = 200 mA		135		mV
		$I_{OUT} = 200 \text{ mA}, T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}$			200	mV

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
START-UP TIME <sup>3</sup>	tstart-up	V <sub>OUT</sub> = 3.3 V		180		μs
CURRENT-LIMIT THRESHOLD⁴	I <sub>LIMIT</sub>	$T_J = 0^{\circ}C \text{ to } +125^{\circ}C$	220	300	400	mA
UNDERVOLTAGE LOCKOUT		$T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}$				
Input Voltage Rising	UVLO <sub>RISE</sub>				1.96	V
Input Voltage Falling	UVLOFALL		1.28			V
Hysteresis	UVLO <sub>HYS</sub>			120		mV
THERMAL SHUTDOWN						
Thermal Shutdown Threshold	TS <sub>SD</sub>	T₁rising		150		°C
Thermal Shutdown Hysteresis	TS <sub>SD-HYS</sub>			15		°C
EN INPUT						
EN Input Logic High	VIH	$2.2 \text{ V} \le \text{V}_{\text{IN}} \le 5.5 \text{ V}$	1.2			V
EN Input Logic Low	V <sub>IL</sub>	$2.2 \text{ V} \le \text{V}_{\text{IN}} \le 5.5 \text{ V}$			0.4	V
EN Input Pull-Down Resistance	R <sub>EN</sub>	$V_{IN} = V_{EN} = 5.5 \text{ V}$		2.6		ΜΩ
OUTPUT NOISE	OUT <sub>NOISE</sub>	10 Hz to 100 kHz, $V_{IN} = 5 \text{ V}$ , $V_{OUT} = 3.3 \text{ V}$		9		μV rms
		10 Hz to 100 kHz, $V_{IN} = 5 \text{ V}$ , $V_{OUT} = 2.5 \text{ V}$		9		μV rms
		10 Hz to 100 kHz, $V_{IN} = 5 \text{ V}$ , $V_{OUT} = 1.1 \text{ V}$		9		μV rms
POWER SUPPLY REJECTION RATIO	PSRR					
$V_{IN} = V_{OUT} + 0.5 V$		10 kHz, $V_{IN} = 3.8 \text{ V}$ , $V_{OUT} = 3.3 \text{ V}$ , $I_{OUT} = 10 \text{ mA}$		70		dB
		$100 \text{ kHz}$ , $V_{IN} = 3.8 \text{ V}$ , $V_{OUT} = 3.3 \text{ V}$ , $I_{OUT} = 10 \text{ mA}$		55		dB
$V_{IN} = V_{OUT} + 1 V$		10 kHz, $V_{IN} = 4.3 \text{ V}$ , $V_{OUT} = 3.3 \text{ V}$ , $I_{OUT} = 10 \text{ mA}$		70		dB
		100 kHz, $V_{IN} = 4.3 \text{ V}$ , $V_{OUT} = 3.3 \text{ V}$ , $I_{OUT} = 10 \text{ mA}$		55		dB
		10 kHz, $V_{IN} = 2.2 \text{ V}$ , $V_{OUT} = 1.1 \text{ V}$ , $I_{OUT} = 10 \text{ mA}$		70		dB
		$100 \text{ kHz}$ , $V_{IN} = 2.2 \text{ V}$ , $V_{OUT} = 1.1 \text{ V}$ , $I_{OUT} = 10 \text{ mA}$		55		dB

<sup>1</sup> Based on an end-point calculation using 0.1 mA and 200 mA loads. See Figure 8 for typical load regulation performance for loads less than 1 mA.

## INPUT AND OUTPUT CAPACITOR, RECOMMENDED SPECIFICATIONS

Table 2.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Minimum Input and Output Capacitance <sup>1</sup>	Смім	$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	0.7			μF
Capacitor ESR	R <sub>ESR</sub>	$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	0.001		0.2	Ω

<sup>&</sup>lt;sup>1</sup> The minimum input and output capacitance should be greater than 0.7 μF over the full range of operating conditions. The full range of operating conditions in the application must be considered during device selection to ensure that the minimum capacitance specification is met. X7R and X5R type capacitors are recommended; Y5V and Z5U capacitors are not recommended for use with any LDO.

<sup>&</sup>lt;sup>2</sup> Dropout voltage is defined as the input-to-output voltage differential when the input voltage is set to the nominal output voltage. This applies only for output voltages above 2.2 V.

 $<sup>^3</sup>$  Start-up time is defined as the time between the rising edge of EN and  $V_{OUT}$  being at 90% of its nominal value.

<sup>&</sup>lt;sup>4</sup> Current-limit threshold is defined as the current at which the output voltage drops to 90% of the specified typical value. For example, the current limit for a 3.0 V output voltage is defined as the current that causes the output voltage to drop to 90% of 3.0 V (that is, 2.7 V).

## **ABSOLUTE MAXIMUM RATINGS**

Table 3.

Parameter	Rating
VIN to GND	-0.3 V to +6.5 V
VOUT to GND	–0.3 V to VIN
EN to GND	-0.3 V to +6.5V
Storage Temperature Range	−65°C to +150°C
Operating Junction Temperature Range	−40°C to +125°C
Operating Ambient Temperature Range	−40°C to +125°C
Soldering Conditions	JEDEC J-STD-020

Stresses above those listed under absolute maximum ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### THERMAL DATA

Absolute maximum ratings apply individually only, not in combination. The ADP151 can be damaged when the junction temperature limits are exceeded. Monitoring ambient temperature does not guarantee that T<sub>1</sub> is within the specified temperature limits. In applications with high power dissipation and poor thermal resistance, the maximum ambient temperature may have to be derated.

In applications with moderate power dissipation and low PCB thermal resistance, the maximum ambient temperature can exceed the maximum limit as long as the junction temperature is within specification limits. The junction temperature ( $T_J$ ) of the device is dependent on the ambient temperature ( $T_A$ ), the power dissipation of the device ( $P_D$ ), and the junction-to-ambient thermal resistance of the package ( $\theta_{JA}$ ).

The maximum junction temperature  $(T_J)$  is calculated from the ambient temperature  $(T_A)$  and power dissipation  $(P_D)$  using the formula

$$T_I = T_A + (P_D \times \theta_{IA})$$

The junction-to-ambient thermal resistance  $(\theta_{JA})$  of the package is based on modeling and calculation using a 4-layer board. The junction-to-ambient thermal resistance is highly dependent on the application and board layout. In applications where high maximum power dissipation exists, close attention to thermal board design is required. The value of  $\theta_{JA}$  may vary, depending

on PCB material, layout, and environmental conditions. The specified values of  $\theta_{IA}$  are based on a 4-layer, 4 in. × 3 in. circuit board. See JESD51-7 and JESD51-9 for detailed information on the board construction. For additional information, see the AN-617 Application Note,  $MicroCSP^{rs}$  Wafer Level Chip Scale Package, available at www.analog.com.

 $\Psi_{JB}$  is the junction-to-board thermal characterization parameter with units of °C/W.  $\Psi_{JB}$  of the package is based on modeling and calculation using a 4-layer board. The JESD51-12, *Guidelines for Reporting and Using Electronic Package Thermal Information*, states that thermal characterization parameters are not the same as thermal resistances.  $\Psi_{JB}$  measures the component power flowing through multiple thermal paths rather than a single path as in thermal resistance,  $\theta_{JB}$ . Therefore,  $\Psi_{JB}$  thermal paths include convection from the top of the package as well as radiation from the package, factors that make  $\Psi_{JB}$  more useful in real-world applications. Maximum junction temperature  $(T_J)$  is calculated from the board temperature  $(T_B)$  and power dissipation  $(P_D)$  using the formula

$$T_I = T_B + (P_D \times \Psi_{IB})$$

See JESD51-8 and JESD51-12 for more detailed information about  $\Psi_{\text{IB}}.$ 

#### THERMAL RESISTANCE

 $\theta_{JA}$  and  $\Psi_{JB}$  are specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

**Table 4. Thermal Resistance** 

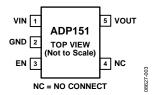
Package Type	θја	Ψјβ	Unit
5-Lead TSOT	170	43	°C/W
4-Ball, 0.4 mm Pitch WLCSP	260	58	°C/W
6-Lead 2 mm × 2 mm LFCSP	63.6	28.3	°C/W

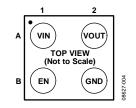
#### **ESD CAUTION**



**ESD (electrostatic discharge) sensitive device.**Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

# PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS





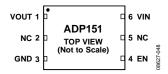


Figure 4. 5-Lead TSOT Pin Configuration

Figure 5. 4-Ball WLCSP Pin Configuration

NOTES
1. NC = NO CONNECT. DO NOT CONNECT TO THIS PIN.
2. THE EXPOSED PAD MUST BE CONNECTED TO GROUND.

Figure 6. 6-Lead LFCSP Pin Configuration

**Table 5. Pin Function Descriptions** 

Pin No.		Pin No.		
TSOT	WLCSP	LFCSP	Mnemonic	Description
1	A1	6	VIN	Regulator Input Supply. Bypass VIN to GND with a 1 μF or greater capacitor.
2	B2	3	GND	Ground.
3	B1	4	EN	Enable Input. Drive EN high to turn on the regulator; drive EN low to turn off the regulator. For automatic startup, connect EN to VIN.
4	N/A	2	NC	No Connect. Not connected internally.
5	A2	1	VOUT	Regulated Output Voltage. Bypass VOUT to GND with a 1 µF or greater capacitor.
N/A	N/A	5	NC	No Connect. Not connected internally.
N/A	N/A		EPAD	Exposed Pad. The exposed pad must be connected to ground. The exposed pad enhances the thermal performance of the package.

## TYPICAL PERFORMANCE CHARACTERISTICS

 $V_{IN} = 5$  V,  $V_{OUT} = 3.3$  V,  $I_{OUT} = 1$  mA,  $C_{IN} = C_{OUT} = 1$   $\mu$ F,  $T_A = 25$ °C, unless otherwise noted.

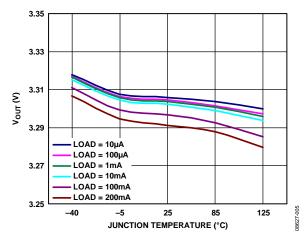


Figure 7. Output Voltage vs. Junction Temperature

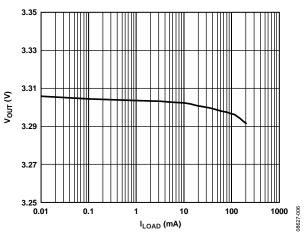


Figure 8. Output Voltage vs. Load Current

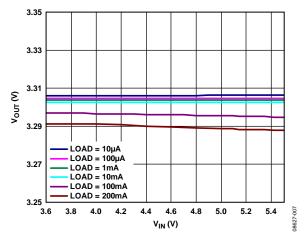


Figure 9. Output Voltage vs. Input Voltage

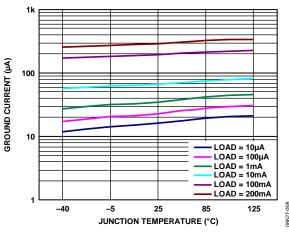


Figure 10. Ground Current vs. Junction Temperature

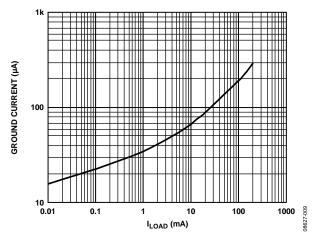


Figure 11. Ground Current vs. Load Current

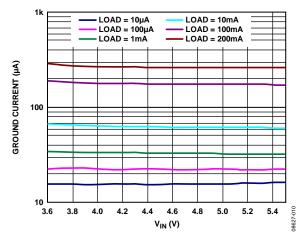


Figure 12. Ground Current vs. Input Voltage

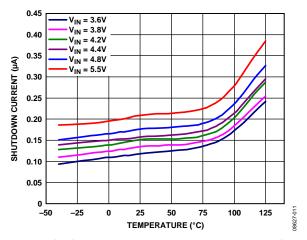


Figure 13. Shutdown Current vs. Temperature at Various Input Voltages

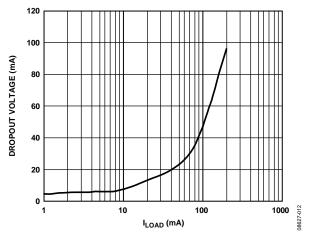


Figure 14. Dropout Voltage vs. Load Current

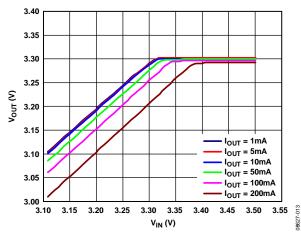


Figure 15. Output Voltage vs. Input Voltage (in Dropout)

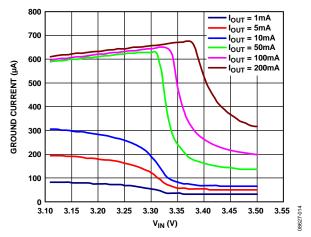


Figure 16. Ground Current vs. Input Voltage (in Dropout)

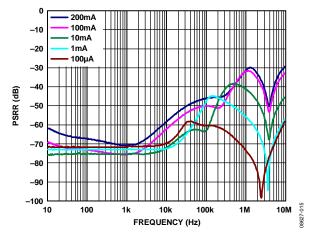


Figure 17. Power Supply Rejection Ratio vs. Frequency,  $V_{OUT} = 1.2 \text{ V}$ ,  $V_{IN} = 2.2 \text{ V}$ 

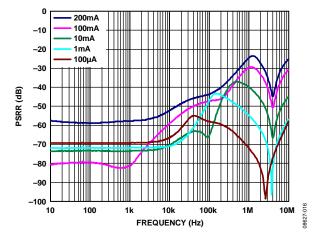


Figure 18. Power Supply Rejection Ratio vs. Frequency,  $V_{OUT} = 2.8 \text{ V}$ ,  $V_{IN} = 3.3 \text{ V}$ 

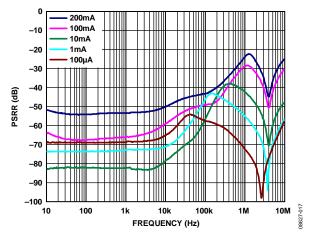


Figure 19. Power Supply Rejection Ratio vs. Frequency,  $V_{OUT} = 3.3 \text{ V}$ ,  $V_{IN} = 3.8 \text{ V}$ 

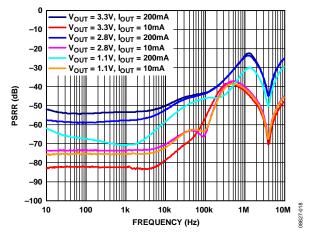


Figure 20. Power Supply Rejection Ratio vs. Frequency at Various Output Voltages and Load Currents,  $V_{OUT}-V_{IN}=0.5$  V, except for  $V_{OUT}=1.1$  V,  $V_{IN}=2.2$  V

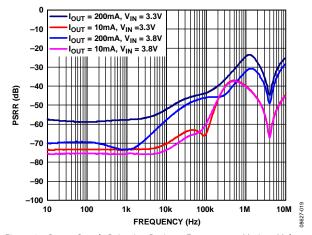


Figure 21. Power Supply Rejection Ratio vs. Frequency at Various Voltages and Load Currents,  $V_{OUT} = 2.8 \text{ V}$ 

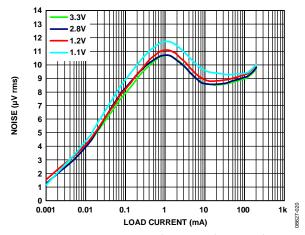


Figure 22. Output Noise vs. Load Current and Output Voltage,  $V_{IN} = 5 \text{ V}, C_{OUT} = 1 \mu F$ 

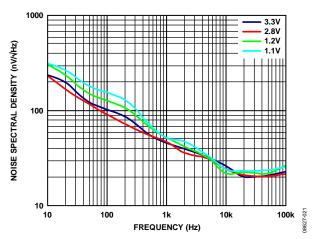


Figure 23. Output Noise Spectral Density vs. Frequency,  $V_{IN} = 5 \text{ V}$ ,  $I_{LOAD} = 10 \text{ mA}$ ,  $C_{OUT} = 1 \mu\text{F}$ 

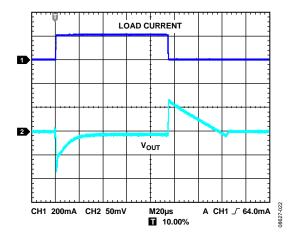


Figure 24. Load Transient Response,  $C_{IN}$ ,  $C_{OUT} = 1 \mu F$ ,  $I_{LOAD} = 1 mA$  to 200 mA

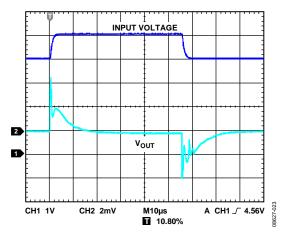


Figure 25. Line Transient Response,  $C_{IN}$ ,  $C_{OUT} = 1 \mu F$ ,  $I_{LOAD} = 200 \text{ mA}$ 

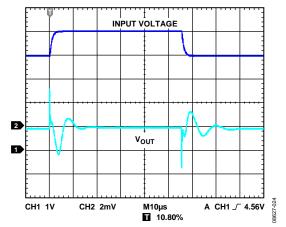


Figure 26. Line Transient Response,  $C_{IN}$ ,  $C_{OUT} = 1 \mu F$ ,  $I_{LOAD} = 1 mA$ 

## THEORY OF OPERATION

The ADP151 is an ultralow noise, low quiescent current, low dropout linear regulator that operates from 2.2 V to 5.5 V and can provide up to 200 mA of output current. Drawing a low 265  $\mu$ A of quiescent current (typical) at full load makes the ADP151 ideal for battery-operated portable equipment. Shutdown current consumption is typically 200 nA.

Using new innovative design techniques, the ADP151 provides superior noise performance for noise-sensitive analog and RF applications without the need for a noise bypass capacitor. The ADP151 is also optimized for use with small 1  $\mu F$  ceramic capacitors.

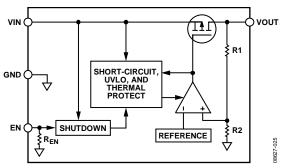


Figure 27. Internal Block Diagram

Internally, the ADP151 consists of a reference, an error amplifier, a feedback voltage divider, and a PMOS pass transistor. Output current is delivered via the PMOS pass device, which is controlled by the error amplifier. The error amplifier compares the reference voltage with the feedback voltage from the output and amplifies the difference. If the feedback voltage is lower than the reference voltage, the gate of the PMOS device is pulled lower, allowing more current to pass and increasing the output voltage. If the feedback voltage is higher than the reference voltage, the gate of the PMOS device is pulled higher, allowing less current to pass and decreasing the output voltage.

An internal pull-down resistor on the EN input holds the input low when the pin is left open.

The ADP151 is available in 16 output voltage options, ranging from 1.1 V to 3.3 V. The ADP151 uses the EN pin to enable and disable the VOUT pin under normal operating conditions. When EN is high, VOUT turns on; when EN is low, VOUT turns off. For automatic startup, EN can be tied to VIN.

## APPLICATIONS INFORMATION

#### **CAPACITOR SELECTION**

### **Output Capacitor**

The ADP151 is designed for operation with small, space-saving ceramic capacitors but can function with most commonly used capacitors as long as care is taken with regard to the effective series resistance (ESR) value. The ESR of the output capacitor affects the stability of the LDO control loop. A minimum of 1  $\mu F$  capacitance with an ESR of 1  $\Omega$  or less is recommended to ensure the stability of the ADP151. Transient response to changes in load current is also affected by output capacitance. Using a larger value of output capacitance improves the transient response of the ADP151 to large changes in load current. Figure 28 shows the transient responses for an output capacitance value of 1  $\mu F$ .

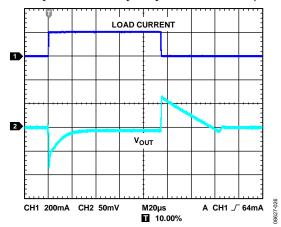


Figure 28. Output Transient Response,  $C_{OUT} = 1 \mu F$ 

### **Input Bypass Capacitor**

Connecting a 1  $\mu F$  capacitor from VIN to GND reduces the circuit sensitivity to the printed circuit board (PCB) layout, especially when long input traces or high source impedance are encountered. If greater than 1  $\mu F$  of output capacitance is required, the input capacitor should be increased to match it.

#### **Input and Output Capacitor Properties**

Any good quality ceramic capacitor can be used with the ADP151, as long as it meets the minimum capacitance and maximum ESR requirements. Ceramic capacitors are manufactured with a variety of dielectrics, each with different behavior over temperature and applied voltage. Capacitors must have an adequate dielectric to ensure the minimum capacitance over the necessary temperature range and dc bias conditions. X5R or X7R dielectrics with a voltage rating of 6.3 V or 10 V are recommended. Y5V and Z5U dielectrics are not recommended, due to their poor temperature and dc bias characteristics.

Figure 29 depicts the capacitance vs. voltage bias characteristic of an 0402, 1  $\mu$ F, 10 V X5R capacitor. The voltage stability of a capacitor is strongly influenced by the capacitor size and voltage rating. In general, a capacitor in a larger package or higher voltage rating exhibits better stability. The temperature variation of the X5R dielectric is ~ $\pm$ 15% over the  $-40^{\circ}$ C to  $+85^{\circ}$ C temperature range and is not a function of package or voltage rating.

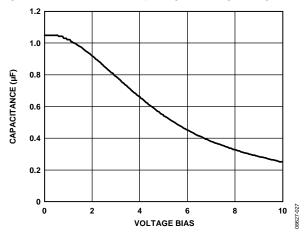


Figure 29. Capacitance vs. Voltage Bias Characteristic

Use Equation 1 to determine the worst-case capacitance, accounting for capacitor variation over temperature, component tolerance, and voltage.

$$C_{EFF} = C_{BIAS} \times (1 - TEMPCO) \times (1 - TOL) \tag{1}$$

where

*C<sub>BIAS</sub>* is the effective capacitance at the operating voltage. *TEMPCO* is the worst-case capacitor temperature coefficient. *TOL* is the worst-case component tolerance.

In this example, the worst-case temperature coefficient (TEMPCO) over  $-40^{\circ}$ C to  $+85^{\circ}$ C is assumed to be 15% for an X5R dielectric. The tolerance of the capacitor (TOL) is assumed to be 10%, and C<sub>BIAS</sub> is 0.94  $\mu$ F at 1.8 V, as shown in Figure 29.

Substituting these values in Equation 1 yields

$$C_{EFF} = 0.94 \,\mu\text{F} \times (1 - 0.15) \times (1 - 0.1) = 0.719 \,\mu\text{F}$$

Therefore, the capacitor chosen in this example meets the minimum capacitance requirement of the LDO over temperature and tolerance at the chosen output voltage.

To guarantee the performance of the ADP151, it is imperative that the effects of dc bias, temperature, and tolerances on the behavior of the capacitors be evaluated for each application.

#### **ENABLE FEATURE**

The ADP151 uses the EN pin to enable and disable the VOUT pin under normal operating conditions. As shown in Figure 30, when a rising voltage on EN crosses the active threshold, VOUT turns on. When a falling voltage on EN crosses the inactive threshold, VOUT turns off.

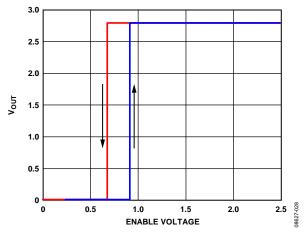


Figure 30. ADP151 Typical EN Pin Operation

As shown in Figure 30, the EN pin has hysteresis built in. This prevents on/off oscillations that can occur due to noise on the EN pin as it passes through the threshold points.

The EN pin active/inactive thresholds are derived from the VIN voltage. Therefore, these thresholds vary with changing input voltage. Figure 31 shows typical EN active/inactive thresholds when the input voltage varies from 2.2 V to 5.5 V.

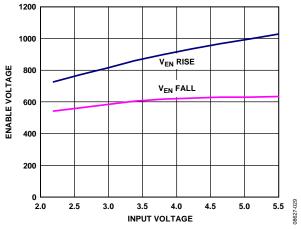


Figure 31. Typical EN Pin Thresholds vs. Input Voltage

The ADP151 uses an internal soft start to limit the inrush current when the output is enabled. The start-up time for the 3.3 V option is approximately 160  $\mu$ s from the time the EN active threshold is crossed to when the output reaches 90% of its final value. As shown in Figure 32, the start-up time is dependent on the output voltage setting.

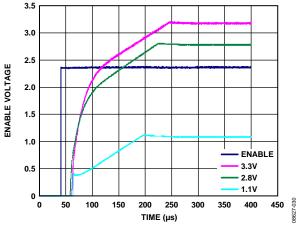


Figure 32. Typical Start-Up Behavior

#### **ADJUSTABLE OUTPUT VOLTAGE OPERATION**

The unique architecture of the ADP151 makes an adjustable version difficult to implement in silicon. However, it is possible to create an adjustable regulator at the expense of increasing the quiescent current of the regulator circuit.

The ADP151, and similar LDOs, are designed to regulate the output voltage,  $V_{\rm OUT}$ , appearing at the VOUT pin with respect to the GND pin. If the GND pin is at a potential other than 0 V (for example, at  $V_{\rm OFFSET}$ ), the ADP151 output voltage is  $V_{\rm OUT}$  +  $V_{\rm OFFSET}$ . By taking advantage of this behavior, it is possible to create an adjustable ADP151 circuit that retains most of the desirable characteristics of the ADP151.

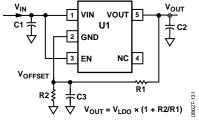


Figure 33. Adjustable LDO Using the ADP151

The circuit shown in Figure 33 is an example of an adjustable LDO using the ADP151. A stable  $V_{\text{OFFSET}}$  voltage is created by passing a known current through R2. The current through R2 is determined by the voltage across R1. Because the voltage across R1 is set by the voltage between VOUT and GND, the current passing through R2 is fixed, and  $V_{\text{OFFSET}}$  is stable.

To minimize the effect variation of the ADP151 ground current ( $I_{\text{GND}}$ ) with load, it is best to keep R1 as small as possible. It is also best to size the current passing through R2 to at least  $20\times$  greater than the maximum expected ground current.

To create a 4 V LDO circuit, start with the 3.3 V version of the ADP151 to minimize the value of R2. Because  $V_{OUT}$  is 4 V,  $V_{OFFSET}$  must be 0.7 V, and the current through R2 must be 7 mA. R1 is, therefore, 3.3 V/7 mA or 471  $\Omega$ . A 470  $\Omega$  standard value introduces less than 1% error. Capacitor C3 is necessary to stabilize the LDO; a value of 1  $\mu$ F is adequate.

Figure 34 through Figure 38 show the typical performance of the 4 V LDO circuit.

The noise performance of the 4 V LDO circuit is only about 1  $\mu$ V worse than the same LDO used at 3.3 V because the output noise of the circuit is almost solely determined by the LDO and not the external components. The small difference may be attributed to the internally generated noise in the LDO ground current working with R2. By keeping R2 small, this noise contribution can be minimized.

The PSRR of the 4 V circuit is as much as 10 dB poorer than the 3.3 V LDO with 500 mV of headroom because the ground current of the LDO varies slightly with input voltage. This, in turn, modulates  $V_{\text{OFFSET}}$  and reduces the PSRR of the regulator. By increasing the headroom to 1 V, the PSRR performance is nearly restored to the performance of the fixed output LDO.

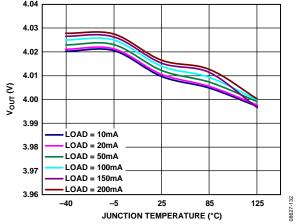


Figure 34. 4 V LDO Circuit, Typical Load Regulation over Temperature

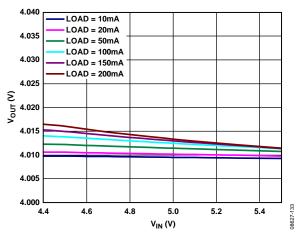


Figure 35. 4 V LDO Circuit, Typical Line Regulation over Load Current

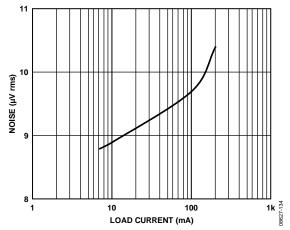


Figure 36. 4 V LDO Circuit, Typical RMS Output Noise, 10 Hz to 100 kHz

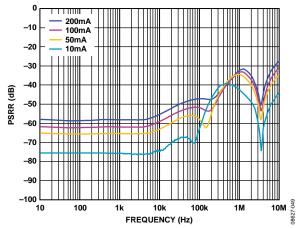


Figure 37. 4 V LDO Circuit, Typical PSRR vs. Load Current, 1 V Headroom

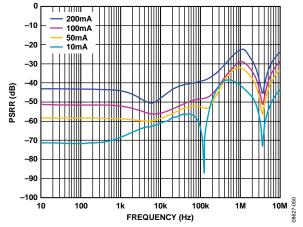


Figure 38. 4 V LDO Circuit, Typical PSRR vs. Load Current, 500 mV Headroom

# CURRENT-LIMIT AND THERMAL OVERLOAD PROTECTION

The ADP151 is protected against damage due to excessive power dissipation by current and thermal overload protection circuits. The ADP151 is designed to current limit when the output load reaches 300 mA (typical). When the output load exceeds 300 mA, the output voltage is reduced to maintain a constant current limit.

Thermal overload protection is included, which limits the junction temperature to a maximum of 150°C (typical). Under extreme conditions (that is, high ambient temperature and power dissipation) when the junction temperature starts to rise above 150°C, the output is turned off, reducing the output current to 0. When the junction temperature drops below 135°C, the output is turned on again, and output current is restored to its nominal value.

Consider the case where a hard short from VOUT to ground occurs. At first, the ADP151 current limits, so that only 300 mA is conducted into the short. If self-heating of the junction causes its temperature to rise above 150°C, thermal shutdown activates, turning off the output and reducing the output current to 0. As the junction temperature cools and drops below 135°C, the output turns on and conducts 300 mA into the short, again causing the junction temperature to rise above 150°C. This thermal oscillation between 135°C and 150°C causes a current oscillation between 300 mA and 0 mA that continues as long as the short remains at the output.

Current- and thermal-limit protections are intended to protect the device against accidental overload conditions. For reliable operation, device power dissipation must be externally limited so that junction temperatures do not exceed 125°C.

#### THERMAL CONSIDERATIONS

In most applications, the ADP151 does not dissipate much heat due to its high efficiency. However, in applications with a high ambient temperature and a high supply voltage to output voltage differential, the heat dissipated in the package can cause the junction temperature of the die to exceed the maximum junction temperature of 125°C.

When the junction temperature exceeds 150°C, the converter enters thermal shutdown. It recovers only after the junction temperature has decreased below 135°C to prevent any permanent damage. Therefore, thermal analysis for the chosen application is very important to guarantee reliable performance over all conditions. The junction temperature of the die is the sum of the ambient temperature of the environment and the temperature rise of the package due to the power dissipation, as shown in Equation 2.

To guarantee reliable operation, the junction temperature of the ADP151 must not exceed 125°C. To ensure that the junction temperature stays below this maximum value, the user must be aware of the parameters that contribute to junction temperature changes. These parameters include ambient temperature, power dissipation in the power device, and thermal resistances between the junction and ambient air ( $\theta_{JA}$ ). The  $\theta_{JA}$  number is dependent on the package assembly compounds that are used and the amount of copper used to solder the package GND pins to the PCB.

Table 6 shows typical  $\theta_{JA}$  values of the 5-lead TSOT, 6-lead LFCSP, and 4-ball WLCSP packages for various PCB copper sizes. Table 7 shows the typical  $\Psi_{JB}$  values of the 5-lead TSOT, 6-lead LFCSP, and 4-ball WLCSP.

Table 6. Typical  $\theta_{JA}$  Values

	θ <sub>JA</sub> (°C/W)			
Copper Size (mm²)	TSOT	WLCSP	LFCSP	
O <sup>1</sup>	170	260	231.2	
50	152	159	161.8	
100	146	157	150.1	
300	134	153	111.5	
500	131	151	91.8	

<sup>&</sup>lt;sup>1</sup> Device soldered to minimum size pin traces.

Table 7. Typical Ψ<sub>JB</sub> Values

Model	Ψ <sub>JB</sub> (°C/W)	
TSOT	43	
WLCSP	58	
LFCSP	28.3	

The junction temperature of the ADP151 can be calculated from the following equation:

$$T_J = T_A + (P_D \times \theta_{JA}) \tag{2}$$

where:

 $T_A$  is the ambient temperature.

 $P_D$  is the power dissipation in the die, given by

$$P_D = [(V_{IN} - V_{OUT}) \times I_{LOAD}] + (V_{IN} \times I_{GND})$$
(3)

where:

 $I_{LOAD}$  is the load current.

 $I_{GND}$  is the ground current.

 $V_{IN}$  and  $V_{OUT}$  are input and output voltages, respectively.

Power dissipation due to ground current is quite small and can be ignored. Therefore, the junction temperature equation simplifies to the following:

$$T_{J} = T_{A} + \{ [(V_{IN} - V_{OUT}) \times I_{LOAD}] \times \theta_{JA} \}$$

$$\tag{4}$$

As shown in Equation 4, for a given ambient temperature, input-to-output voltage differential, and continuous load current, there exists a minimum copper size requirement for the PCB to ensure that the junction temperature does not rise above 125°C. Figure 39 through Figure 59 show junction temperature calculations for various ambient temperatures, load currents,  $V_{\rm IN}$ -to- $V_{\rm OUT}$  differentials, and areas of PCB copper.

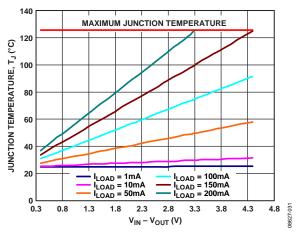


Figure 39. WLCSP 500 mm<sup>2</sup> of PCB Copper,  $T_A = 25$ °C

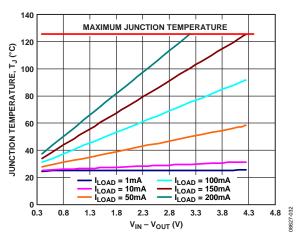


Figure 40. WLCSP 100 mm<sup>2</sup> of PCB Copper,  $T_A = 25$ °C

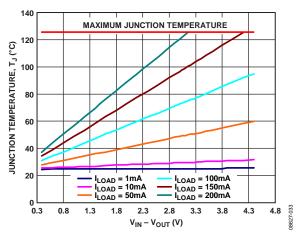


Figure 41. WLCSP 50 mm<sup>2</sup> of PCB Copper,  $T_A = 25$ °C

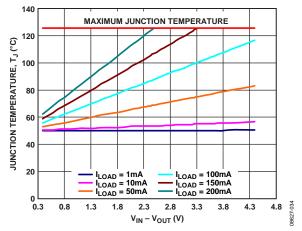


Figure 42. WLCSP 500 mm<sup>2</sup> of PCB Copper,  $T_A = 50$ °C

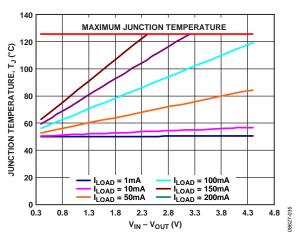


Figure 43. WLCSP 100 mm<sup>2</sup> of PCB Copper,  $T_A = 50$ °C

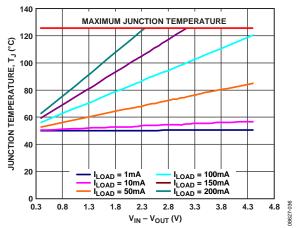


Figure 44. WLCSP 50 mm<sup>2</sup> of PCB Copper,  $T_A = 50^{\circ}$ C

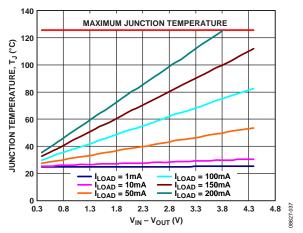


Figure 45. TSOT 500 mm<sup>2</sup> of PCB Copper,  $T_A = 25$ °C

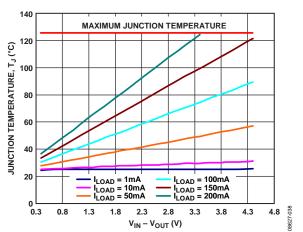


Figure 46. TSOT 100 mm<sup>2</sup> of PCB Copper,  $T_A = 25^{\circ}\text{C}$ 

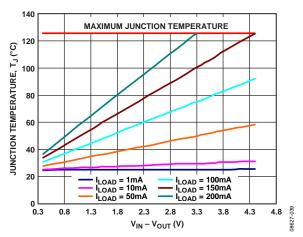


Figure 47. TSOT 50 mm<sup>2</sup> of PCB Copper,  $T_A = 25$ °C

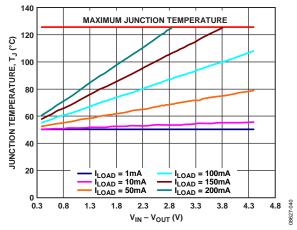


Figure 48. TSOT 500 mm<sup>2</sup> of PCB Copper,  $T_A = 50$ °C

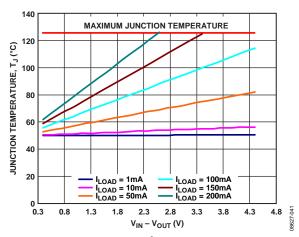


Figure 49. TSOT 100 mm<sup>2</sup> of PCB Copper,  $T_A = 50$ °C

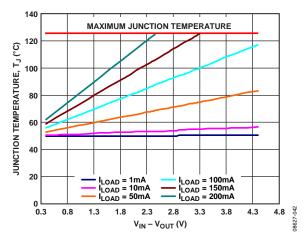


Figure 50. TSOT 50 mm<sup>2</sup> of PCB Copper,  $T_A = 50$ °C

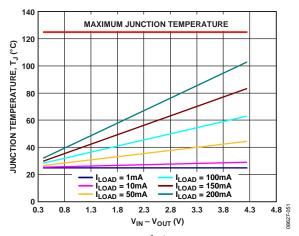


Figure 51. LFCSP 500 mm<sup>2</sup> of PCB Copper,  $T_A = 25$ °C

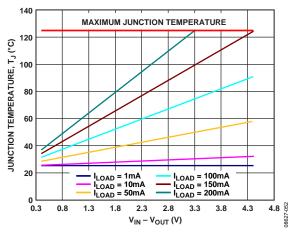


Figure 52. LFCSP 100 mm<sup>2</sup> of PCB Copper,  $T_A = 25$ °C

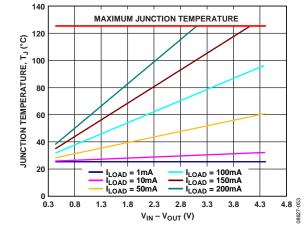


Figure 53. LFCSP 50 mm<sup>2</sup> of PCB Copper,  $T_A = 25$ °C

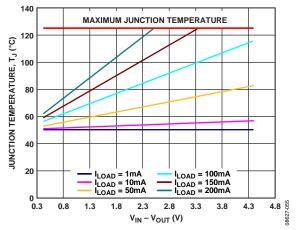


Figure 54. LFCSP 500 mm<sup>2</sup> of PCB Copper,  $T_A = 50$ °C

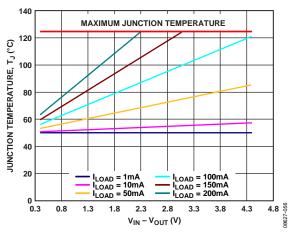


Figure 55. LFCSP 100 mm<sup>2</sup> of PCB Copper,  $T_A = 50$ °C

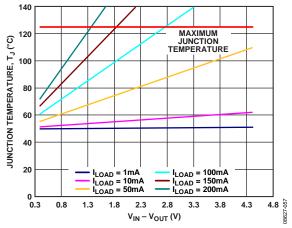


Figure 56. LFCSP 50 mm<sup>2</sup> of PCB Copper,  $T_A = 50$ °C

120

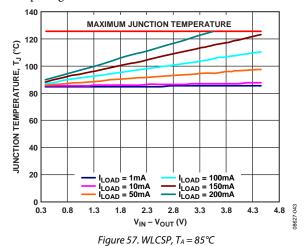
100

40

In the case where the board temperature is known, use the thermal characterization parameter,  $\Psi_{JB}$ , to estimate the junction temperature rise (see Figure 57 and Figure 58). Maximum junction temperature (T<sub>J</sub>) is calculated from the board temperature (TB) and power dissipation (PD) using the following formula:

$$T_{J} = T_{B} + (P_{D} \times \Psi_{JB}) \tag{5}$$

The typical value of  $\Psi_{IB}$  is 58°C/W for the 4-ball WLCSP package, 43°C/W for the 5-lead TSOT package, and 28.3°C/W for the 6-lead LFCSP package.



JUNCTION TEMPERATURE, TJ (°C) I<sub>LOAD</sub> = 1mA I<sub>LOAD</sub> = 10mA I<sub>LOAD</sub> = 50mA I<sub>LOAD</sub> = 100mA I<sub>LOAD</sub> = 150mA I<sub>LOAD</sub> = 200mA 0.3 1.3 2.3 2.8 8.0 4.3 4.8  $V_{IN} - V_{OUT}(V)$ Figure 58. TSOT,  $T_A = 85^{\circ}C$ 140 MAXIMUM JUNCTION TEMPERATURE 120 JUNCTION TEMPERATURE, TJ (°C) 100 60

MAXIMUM JUNCTION TEMPERATURE

 $V_{IN} - V_{OUT}(V)$ 

I<sub>LOAD</sub> = 1mA I<sub>LOAD</sub> = 10mA I<sub>LOAD</sub> = 50mA

I<sub>LOAD</sub> = 100mA I<sub>LOAD</sub> = 150mA I<sub>LOAD</sub> = 200mA

## PRINTED CIRCUIT BOARD LAYOUT CONSIDERATIONS

Heat dissipation from the package can be improved by increasing the amount of copper attached to the pins of the ADP151. However, as listed in Table 6, a point of diminishing returns is eventually reached, beyond which an increase in the copper size does not yield significant heat dissipation benefits.

Place the input capacitor as close as possible to the VIN and GND pins. Place the output capacitor as close as possible to the VOUT and GND pins. Use of 0402 or 0603 size capacitors and resistors achieves the smallest possible footprint solution on boards where area is limited.

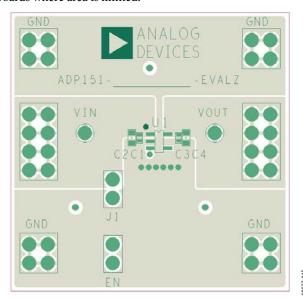


Figure 60. Example TSOT PCB Layout

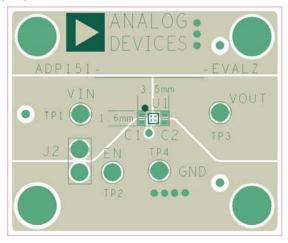


Figure 61. Example WLCSP PCB Layout

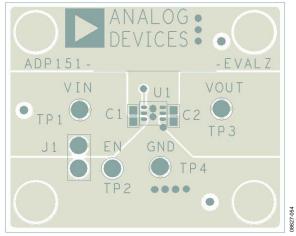


Figure 62. Example LFCSP PCB Layout

## **OUTLINE DIMENSIONS**

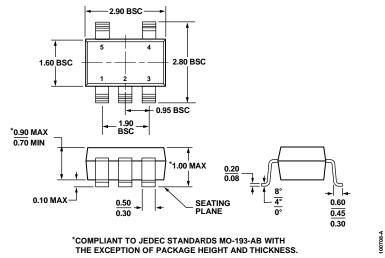


Figure 63. 5-Lead Thin Small Outline Transistor Package [TSOT] (UJ-5) Dimensions show in millimeters

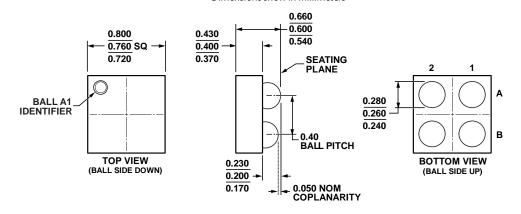


Figure 64. 4-Ball Wafer Level Chip Scale Package [WLCSP] (CB-4-3)

011509-A

Dimensions show in millimeters

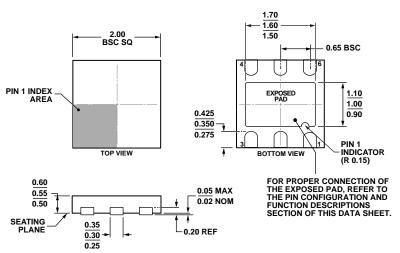


Figure 65. 6-Lead Lead Frame Chip Scale Package [LFCSP\_UD] 2.00 mm  $\times$  2.00 mm Body, Ultra Thin, Dual Lead (CP-6-3)

Dimensions show in millimeters

Rev. E | Page 21 of 24

## **ORDERING GUIDE**

Model <sup>1</sup>	Temperature Range	Output Voltage (V) <sup>2</sup>	Package Description	Package Option <sup>3</sup>	Branding
ADP151ACBZ-1.1-R7	-40°C to +125°C	1.1	4-Ball WLCSP	CB-4-1	8R
ADP151ACBZ-1.2-R7	-40°C to +125°C	1.2	4-Ball WLCSP	CB-4-3	4R
ADP151ACBZ-1.5-R7	-40°C to +125°C	1.5	4-Ball WLCSP	CB-4-3	4S
ADP151ACBZ-1.8-R7	-40°C to +125°C	1.8	4-Ball WLCSP	CB-4-3	4T
ADP151ACBZ-2.5-R7	-40°C to +125°C	2.5	4-Ball WLCSP	CB-4-3	4U
ADP151ACBZ-2.6-R7	-40°C to +125°C	2.6	4-Ball WLCSP	CB-4-3	8Q
ADP151ACBZ-2.75-R7	-40°C to +125°C	2.75	4-Ball WLCSP	CB-4-3	4V
ADP151ACBZ-2.8-R7	-40°C to +125°C	2.8	4-Ball WLCSP	CB-4-3	4X
ADP151ACBZ-2.85-R7	-40°C to +125°C	2.85	4-Ball WLCSP	CB-4-3	4Y
ADP151ACBZ-3.0-R7	-40°C to +125°C	3.0	4-Ball WLCSP	CB-4-3	4Z
ADP151ACBZ-3.3-R7	-40°C to +125°C	3.3	4-Ball WLCSP	CB-4-3	50
ADP151ACBZ-2.1-R7	-40°C to +125°C	2.1	4-Ball WLCSP	CB-4-3	5E
ADP151AUJZ-1.2-R7	-40°C to +125°C	1.2	5-Lead TSOT	UJ-5	LF6
ADP151AUJZ-1.5-R7	-40°C to +125°C	1.5	5-Lead TSOT	UJ-5	LF7
ADP151AUJZ-1.8-R7	-40°C to +125°C	1.8	5-Lead TSOT	UJ-5	LF8
ADP151AUJZ-2.5-R7	-40°C to +125°C	2.5	5-Lead TSOT	UJ-5	LF9
ADP151AUJZ-2.8-R7	-40°C to +125°C	2.8	5-Lead TSOT	UJ-5	LFG
ADP151AUJZ-3.0-R7	-40°C to +125°C	3.0	5-Lead TSOT	UJ-5	LFH
ADP151AUJZ-3.3-R7	-40°C to +125°C	3.3	5-Lead TSOT	UJ-5	LFJ
ADP151ACPZ-1.2-R7	-40°C to +125°C	1.2	6-Lead LFCSP_UD	CP-6-3	LF6
ADP151ACPZ-1.5-R7	-40°C to +125°C	1.5	6-Lead LFCSP_UD	CP-6-3	LF7
ADP151ACPZ-1.8-R7	-40°C to +125°C	1.8	6-Lead LFCSP_UD	CP-6-3	LF8
ADP151ACPZ-2.5-R7	-40°C to +125°C	2.5	6-Lead LFCSP_UD	CP-6-3	LF9
ADP151ACPZ-2.7-R7	-40°C to +125°C	2.7	6-Lead LFCSP_UD	CP-6-3	LKZ
ADP151ACPZ-2.8-R7	-40°C to +125°C	2.8	6-Lead LFCSP_UD	CP-6-3	LFG
ADP151ACPZ-3.0-R7	-40°C to +125°C	3.0	6-Lead LFCSP_UD	CP-6-3	LFH
ADP151ACPZ-3.3-R7	-40°C to +125°C	3.3	6-Lead LFCSP_UD	CP-6-3	LFJ
ADP151UJZ-REDYKIT			Evaluation Board Kit		
ADP151CPZ-REDYKIT			Evaluation Board Kit		
ADP151CB-3.3-EVALZ			Evaluation Board		

 $<sup>^{1}</sup>$  Z = RoHS Compliant Part.

<sup>&</sup>lt;sup>2</sup>For additional voltage options for the ADP151ACBZ package option, contact a local Analog Devices, Inc., sales or distribution representative. <sup>3</sup> The ADP151ACBZ package option is halide free.

# **NOTES**

**NOTES**